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SN74LV08A

SCLS387M-SEPTEMBER 1997-REVISED OCTOBER 2014

SN74LV08A Quadruple 2-Input Positive-AND Gates

1 Features

- 2-V to 5.5-V V_{CC} Operation
- Max t_{pd} of 7 ns at 5 V
- Typical V_{OLP} (Output Ground Bounce)
 < 0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot) > 2.3 V at V_{CC} = 3.3 V, T_A = 25° C
- Support Mixed-Mode Voltage Operation on All Ports
- I_{off} Supports Live Insertion, Partial-Power-Down Mode, and Back-Drive Protection
- Latch-Up Performance Exceeds 250 mA
 Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model
 - 200-V Machine Model
 - 1000-V Charged-Device Model

2 Applications

- Servers
- Telecom Infrastructure
- PCs and Notebooks
- TV Set-Top Boxes

3 Description

This quadruple 2-input positive-AND gate is designed for 2-V to 5.5-V V_{CC} operation. The SN74LV08A device performs the Boolean function $Y = A \cdot B$ or $Y = \overline{A + \overline{B}}$ in positive logic.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
	TVSOP (14)	3.60 mm × 4.40 mm		
	SOIC (14)	8.65 mm × 3.91 mm		
SN74LV08A	VQFN (14)	3.50 mm× 3.50 mm		
	SSOP (14)	6.20 mm × 5.30 mm		
	TSSOP (14)	5.00 mm × 4.40 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.



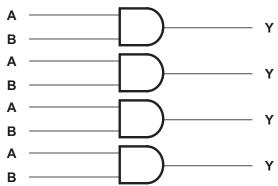


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Revision History

Changes from Revision L (October 2010) to Revision M	Page
Updated document to new TI data sheet format	1
Deleted Ordering Information table.	1
Deleted SN54LV08A device from data sheet	1
Added Applications.	1
Added Pin Functions table	
Added Handling Ratings table	4
• Changed MAX operating temperature to 125°C in Recommended Operating Conditions table.	
Added Thermal Information table.	
Added Typical Characteristics.	
Added Detailed Description section	
Added Application and Implementation section	10
Added Power Supply Recommendations and Layout sections	11

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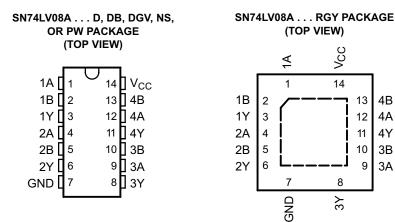
4B

4A

4Y

3A

6 Pin Configuration and Functions



Pin Functions

	PIN		
	SN74LV08A	I/O	DESCRIPTION
NAME	D, DB, DGV, NS, PW, RGY		
1A	1	I	1A Input
1B	2	I	1B Input
1Y	3	0	1Y Output
2A	4	I	2A Input
2B	5	I	2B Input
2Y	6	0	2Y Output
3Y	8	0	3Y Output
ЗA	9	I	3A Input
3B	10	I	3B Input
4Y	11	0	4Y Output
4A	12	I	4A Input
4B	13	I	4B Input
GND	7	—	Ground Pin
V _{CC}	14	_	Power Pin

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	7	V
VI	Input voltage range ⁽²⁾	Input voltage range ⁽²⁾			
Vo	Voltage range applied to any output	Voltage range applied to any output in the high-impedance or power-off state ⁽²⁾			
Vo	Output voltage range ⁽²⁾⁽³⁾		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-20	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
I _O	Continuous output current	$V_{O} = 0$ to V_{CC}		±25	mA
	Continuous current through V_{CC} or G	GND		±50	mA

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) This value is limited to 5.5 V maximum.

7.2 Handling Ratings

			MIN	MAX	UNIT
T _{stg}	Storage temperature rang	ge	-65	150	°C
N	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	0	2000	
V _(ESD)		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	0	1000	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			SN74LV	SN74LV08A			
			MIN	МАХ	UNIT		
V _{CC}	Supply voltage		2	5.5	V		
		$V_{CC} = 2 V$	1.5				
\ <i>\</i>		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	V _{CC} × 0.7		N		
V _{IH}	High-level input voltage	V _{CC} = 3 V to 3.6 V	V _{CC} × 0.7		V		
		V_{CC} = 4.5 V to 5.5 V	V _{CC} × 0.7				
		$V_{CC} = 2 V$		0.5			
		V_{CC} = 2.3 V to 2.7 V		$V_{CC} \times 0.3$	V		
VIL	Low-level input voltage	$V_{CC} = 3 V \text{ to } 3.6 V$		$V_{CC} \times 0.3$	v		
		V_{CC} = 4.5 V to 5.5 V		$V_{CC} \times 0.35$			
VI	Input voltage		0	5.5	V		
Vo	Output voltage		0	V _{CC}	V		
		$V_{CC} = 2 V$		-50	μA		
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		-2			
он	High-level output current	V _{CC} = 3 V to 3.6 V		-6	mA		
		$V_{CC} = 4.5 V \text{ to } 5.5 V$		-12			
		$V_{CC} = 2 V$		50	μA		
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		2			
OL	Low-level output current	V _{CC} = 3 V to 3.6 V		6	mA		
		V_{CC} = 4.5 V to 5.5 V		12			
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		200			
Δt/Δv	Input transition rise and fall rate	V _{CC} = 3 V to 3.6 V		100	ns/V		
		$V_{CC} = 4.5 V \text{ to } 5.5 V$		20			
T _A	Operating free-air temperature		-40	125	°C		

 All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs (SCBA004).

7.4 Thermal Information

					SN74LV08A				
	THERMAL METRIC ⁽¹⁾	D	DB	DGV	N	NS	PW	RGY	UNIT
		14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	
$R_{ extsf{ heta}JA}$	Junction-to-ambient thermal resistance	90.6	107.1	129.0	57.4	90.7	122.6	57.5	
R _{0JC(top)}	Junction-to-case (top) thermal resistance	50.9	59.6	52.1	44.9	48.3	51.4	70.8	
R _{θJB}	Junction-to-board thermal resistance	44.8	54.4	62.0	37.2	49.4	64.4	33.6	10 M
ψ_{JT}	Junction-to-top characterization parameter	14.7	20.5	6.5	30.1	14.6	6.7	3.4	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	44.5	53.8	61.3	37.1	49.1	63.8	33.7	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	-	-	-	-	-	-	13.9	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

7.5 Electrical Characteristics

PARAMETER	TEST CONDITIONS	V _{cc}		LV08A to 85°C		SN74LV08A -40°C to 125°C			
			MIN	TYP M	AX MIN	ТҮР	MAX		
	I _{OH} = -50 μA	2 V to 5.5 V	$V_{CC} - 0.1$		V _{CC} - 0.1				
N	$I_{OH} = -2 \text{ mA}$	2.3 V	2		2			V	
V _{OH}	$I_{OH} = -6 \text{ mA}$	3 V	2.48		2.48			v	
	$I_{OH} = -12 \text{ mA}$	4.5 V	3.8		3.8				
	I _{OL} = 50 μA	2 V to 5.5 V		().1		0.1	0.4 V	
M	I _{OL} = 2 mA	2.3 V		().4		0.4		
V _{OL}	I _{OL} = 6 mA	3 V		0.	44		0.44		
	I _{OL} = 12 mA	4.5 V		0.	55		0.55		
l _l	$V_1 = 5.5 \text{ V or GND}$	0 to 5.5 V			±1		±1	μA	
I _{CC}	$V_{I} = V_{CC} \text{ or } GND, \qquad I_{O} = 0$	5.5 V			20		20	μA	
I _{off}	$V_1 \text{ or } V_0 = 0 \text{ to } 5.5 \text{ V}$	0			5		5	μA	
0		3.3 V		3.3		3.3		- 5	
Ci	$V_{I} = V_{CC}$ or GND	5 V		3.3		3.3		pF	

over recommended operating free-air temperature range (unless otherwise noted)

7.6 Switching Characteristics, V_{cc} = 2.5 V ± 0.2 V

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM	TO	LOAD CAPACITANCE	T,	₄ = 25°C		SN74L\	/08A	SN74I –40°C t		UNIT
(INPU I	(INPUT)	(INPUT) (OUTPUT) C	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
	A or B	V	C _L = 15 pF		7.9 ⁽¹⁾	13.8 ⁽¹⁾	1	16	1	17	20
Lpd	AUIB	r	C _L = 50 pF		10.5	17.3	1	20	1	21	ns

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.

7.7 Switching Characteristics, $V_{CC} = 3.3 V \pm 0.3 V$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM	TO	LOAD CAPACITANCE	т	_A = 25°C		SN74L	V08A	SN74L –40°C to		UNIT
	(INPUT)	UT) (OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
	A at D	V	C _L = 15 pF		5.6 ⁽¹⁾	8.8 ⁽¹⁾	1	10.5	1	11.5	
τ _{pd}	A or B	ř	C _L = 50 pF		7.5	12.3	1	14	1	15	ns

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.

7.8 Switching Characteristics, $V_{CC} = 5 V \pm 0.5 V$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO	LOAD CAPACITANCE	Т	_A = 25°C		SN74L	V08A	SN74L –40°C to		UNIT
	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
	t _{pd} A or B	V	C _L = 15 pF		4.1 ⁽¹⁾	5.9 ⁽¹⁾	1	7	1	8	
t _{pd}		ř	C _L = 50 pF		5.5	7.9	1	9	1	10	ns

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.



SN74I V08A

7.9 Noise Characteristics⁽¹⁾

$V_{CC} = 3.3 \text{ V}, \text{ C}_{L} = 50 \text{ pF}, \text{ T}_{A} = 25^{\circ}\text{C}$	
	PARAMETER

	DADAMETED		UNIT		
	PARAMETER	MIN	TYP	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.2	0.8	V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.1	-0.8	V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		3.1		V
V _{IH(D)}	High-level dynamic input voltage	2.31			V
V _{IL(D)}	Low-level dynamic input voltage			0.99	V

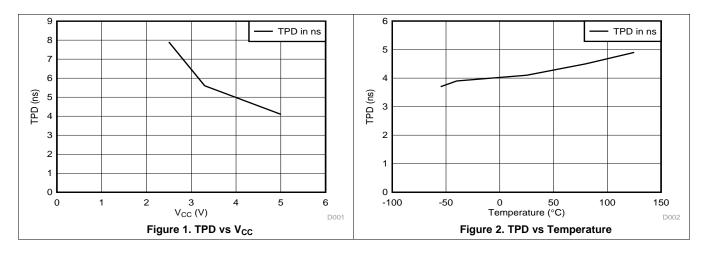
(1) Characteristics are for surface-mount packages only.

7.10 Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST C	CONDITIONS	V _{cc}	TYP	UNIT
C _{pd}	Dever dissinction constitution	C 50 mF	f 10 MU	3.3 V	8	pF
	Power dissipation capacitance	$C_{L} = 50 \text{ pF},$	f = 10 MHz	5 V	10	

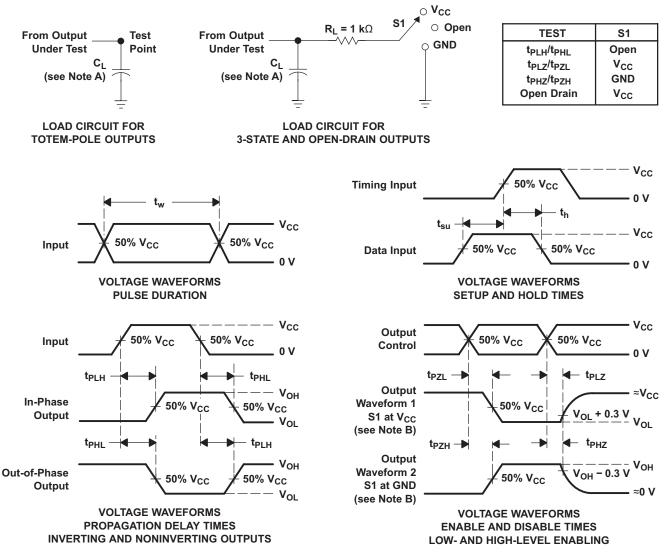
7.11 Typical Characteristics



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8 Parameter Measurement Information



- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control.

Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.

- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z₀ = 50 Ω , t_r \leq 3 ns, t_f \leq 3 ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- ${\sf E}. \quad t_{{\sf PLZ}} \text{ and } t_{{\sf PHZ}} \text{ are the same as } t_{{\sf dis}}.$
- $\label{eq:F.transform} F. \quad t_{PZL} \text{ and } t_{PZH} \text{ are the same as } t_{en}.$
- G. t_{PHL} and t_{PLH} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms



9 Detailed Description

9.1 Overview

This quadruple 2-input positive-AND gate is designed for 2-V to 5.5-V V_{CC} operation. The SN74LA08A device performs the Boolean function $Y = A \cdot B$ or $Y = \overline{A + B}$ in positive logic.

This device is fully specified for partial-power-down application using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down.

9.2 Functional Block Diagram



Figure 4. Logic Diagram, Each Gate (Positive Logic)

9.3 Feature Description

- Wide operating voltage range
 - Operates From 2 V to 5.5 V
- Allows down voltage translation
- Inputs accept voltages to 5.5 V
- I_{off} feature
 - Allows voltages on the input or output when V_{CC} is 0 V

9.4 Device Functional Modes

Table 1. Function Table
(Each Gate)

INP	OUTPUT					
Α	A B					
Н	Н	Н				
L	Х	L				
х	L	L				



10 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

The SN74LV08A is a low-drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The inputs can accept voltages up to 5.5 V at any valid V_{CC} , thus making it ideal for down translation.

10.2 Typical Application

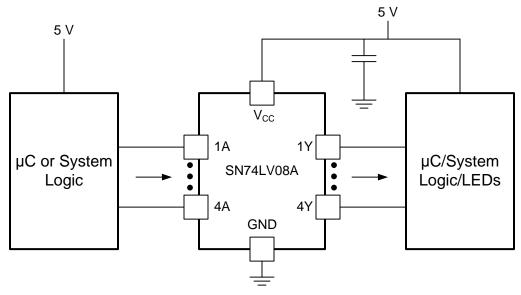


Figure 5. Application Diagram

10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

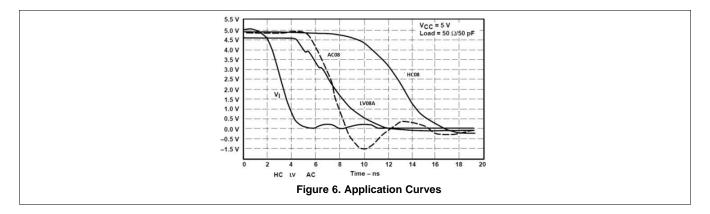
10.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions:
 - For specified high and low levels, see V_{IH} and V_{IL} in *Recommended Operating Conditions* table.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC} .
- 2. Recommend Output Conditions:
 - Load currents should not exceed 25 mA per output and 50 mA total for the part.
 - Outputs should not be pulled above V_{CC}.



Typical Application (continued)

10.2.3 Application Curves



11 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions* table.

Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1 μ F capacitor is recommended. If there are multiple V_{CC} terminals then 0.01 μ F or 0.022 μ F capacitors are recommended for each power terminal. It is ok to parallel multiple bypass capacitors to reject different frequencies of noise. 0.1 μ F and 1.0 μ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for the best results.

12 Layout

12.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in Figure 7 are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} , whichever makes more sense or is more convenient. It is acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the I/Os so they also cannot float when disabled.

12.2 Layout Example

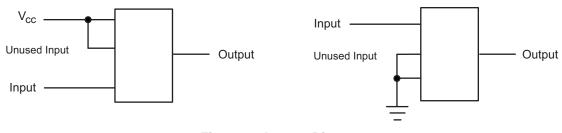


Figure 7. Layout Diagram

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13 Device and Documentation Support

13.1 Trademarks

All trademarks are the property of their respective owners.

13.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



24-Aug-2018

PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•		Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN74LV08AD	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08ADBR	ACTIVE	SSOP	DB	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08ADE4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08ADGVR	ACTIVE	TVSOP	DGV	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08ADR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08ADRE4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08ANSR	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	74LV08A	Samples
SN74LV08APW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08APWG4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08APWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08APWRE4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08APWRG3	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08APWRG4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08APWT	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08APWTG4	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08ARGYR	ACTIVE	VQFN	RGY	14	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	LV08A	Samples
SN74LV08ARGYRG4	ACTIVE	VQFN	RGY	14	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	LV08A	Samples



24-Aug-2018

(1) The marketing status values are defined as follows:
 ACTIVE: Product device recommended for new designs.
 LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
 NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
 PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
 OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74LV08A :

Automotive: SN74LV08A-Q1

• Enhanced Product: SN74LV08A-EP

NOTE: Qualified Version Definitions:



24-Aug-2018

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

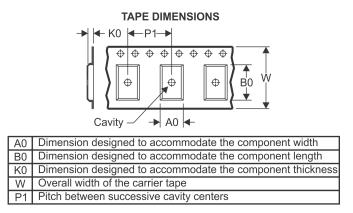
PACKAGE MATERIALS INFORMATION

www.ti.com

Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



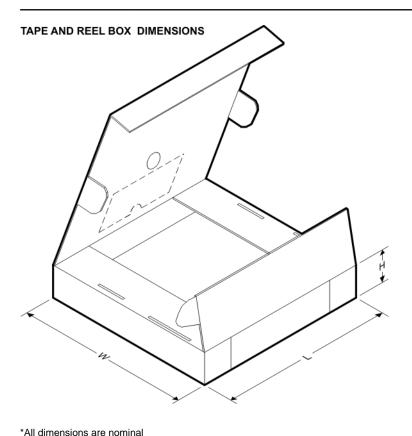
*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV08ADGVR	TVSOP	DGV	14	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
SN74LV08ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LV08APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV08APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV08APWRG3	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV08APWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV08APWT	TSSOP	PW	14	250	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV08ARGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

20-Dec-2018



Device	Device Package Type		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)			
SN74LV08ADGVR	TVSOP	DGV	14	2000	367.0	367.0	35.0			
SN74LV08ADR	SOIC	D	14	2500	367.0	367.0	38.0			
SN74LV08APWR	TSSOP	PW	14	2000	364.0	364.0	27.0			
SN74LV08APWR	TSSOP	PW	14	2000	367.0	367.0	35.0			
SN74LV08APWRG3	TSSOP	PW	14	2000	364.0	364.0	27.0			
SN74LV08APWRG4	TSSOP	PW	14	2000	367.0	367.0	35.0			
SN74LV08APWT	TSSOP	PW	14	250	367.0	367.0	35.0			
SN74LV08ARGYR	VQFN	RGY	14	3000	367.0	367.0	35.0			

MECHANICAL DATA



- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- earrow Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated.
- The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



RGY (S-PVQFN-N14)

PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



NOTE: All linear dimensions are in millimeters





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.

D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.

- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 \bigcirc Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS ** 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G**)

14-PINS SHOWN

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



MECHANICAL DATA

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

DGV (R-PDSO-G**)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



A. An integration of the information o

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



MECHANICAL DATA

MSSO002E - JANUARY 1995 - REVISED DECEMBER 2001

DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



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